

30V N-Channel NexFET™ Power MOSFET

FEATURES

- Qualified for Automotive Applications
- Optimized for 5V Gate Drive
- Ultra Low Q_g and Q_{gd}
- Low Thermal Resistance
- Pb Free
- RoHS Compliant
- Halogen Free
- SON 2-mm x 2-mm Plastic Package

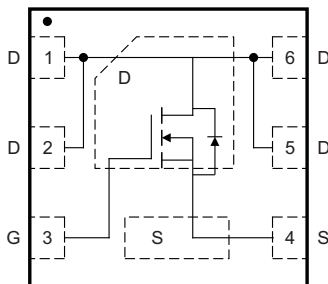
APPLICATIONS

- DC-DC Converters
- Battery and Load Management Applications

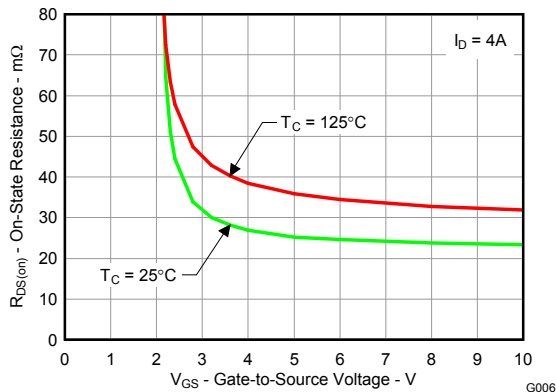
DESCRIPTION

The NexFET power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications. The 2-mm x 2-mm SON offers excellent thermal performance for the size of the package.

Top View



P0108-01

 $R_{DS(on)}$ vs V_{GS}


G006

PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	30	V
Q_g	Gate Charge Total (4.5V)	2.1	nC
Q_{gd}	Gate Charge Gate to Drain	0.4	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 3V$	31 mΩ
		$V_{GS} = 4.5V$	26 mΩ
		$V_{GS} = 8V$	24 mΩ
$V_{GS(th)}$	Threshold Voltage	1.3	V

ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD17313Q2Q1	SON 2-mm x 2-mm Plastic Package	13-Inch Reel	3000	Tape and Reel

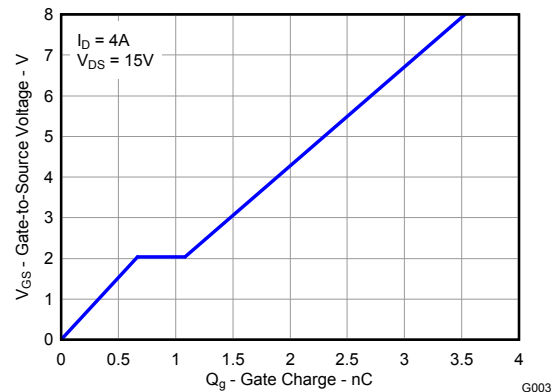
ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ C$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	+10 / -8	V
I_D	Continuous Drain Current, $T_C = 25^\circ C$	5	A
	Continuous Drain Current ⁽¹⁾	5	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ C$ ⁽²⁾	20	A
P_D	Power Dissipation	2.3	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ C$
E_{AS}	Avalanche Energy, Single Pulse, $I_D = 19A, L = 0.1mH, R_G = 25\Omega$	18	mJ

(1) Package Limited

 (2) Pulse duration $\leq 300\mu s$, duty cycle $\leq 2\%$

GATE CHARGE



G003



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise stated)

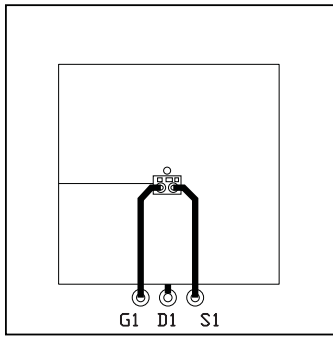
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
V_{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30			V
I_{DSS}	Drain to Source Leakage	$V_{GS} = 0V, V_{DS} = 24V$			1	μA
I_{GSS}	Gate to Source Leakage	$V_{DS} = 0V, V_{GS} = +10 / -8V$			100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.9	1.3	1.8	V
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 3V, I_D = 4A$		31	42	$m\Omega$
		$V_{GS} = 4.5V, I_D = 4A$		26	32	$m\Omega$
		$V_{GS} = 8V, I_D = 4A$		24	30	$m\Omega$
g_{fs}	Transconductance	$V_{DS} = 15V, I_D = 4A$		16		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ $f = 1MHz$		260	340	pF
C_{oss}	Output Capacitance			140	180	pF
C_{rss}	Reverse Transfer Capacitance			13	17	pF
R_G	Series Gate Resistance			1.3	2.6	Ω
Q_g	Gate Charge Total (4.5V)	$V_{DS} = 15V,$ $I_D = 4A$		2.1	2.7	nC
Q_{gd}	Gate Charge – Gate to Drain			0.4		nC
Q_{gs}	Gate Charge Gate to Source			0.7		nC
$Q_{g(th)}$	Gate Charge at V_{th}			0.3		nC
Q_{oss}	Output Charge		$V_{DS} = 13.5V, V_{GS} = 0V$		3.8	
$t_{d(on)}$	Turn On Delay Time	$V_{DS} = 15V, V_{GS} = 4.5V,$ $I_D = 4A, R_G = 2\Omega$		2.8		ns
t_r	Rise Time			3.9		ns
$t_{d(off)}$	Turn Off Delay Time			4.2		ns
t_f	Fall Time			1.3		ns
Diode Characteristics						
V_{SD}	Diode Forward Voltage	$I_{SD} = 4A, V_{GS} = 0V$		0.85	1	V
Q_{rr}	Reverse Recovery Charge	$V_{DD} = 13.5V, I_F = 4A,$ $di/dt = 300A/\mu s$		6.4		nC
t_{rr}	Reverse Recovery Time			12.9		ns

THERMAL CHARACTERISTICS

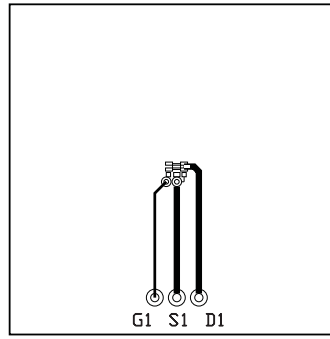
($T_A = 25^\circ\text{C}$ unless otherwise stated)

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			7.4	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			67	$^\circ\text{C/W}$

- (1) $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 67^{\circ}\text{C/W}$
when mounted on
1 inch² (6.45 cm²) of 2-
oz. (0.071-mm thick)
Cu.



Max $R_{\theta JA} = 228^{\circ}\text{C/W}$
when mounted on a
minimum pad area of
2-oz. (0.071-mm thick)
Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)

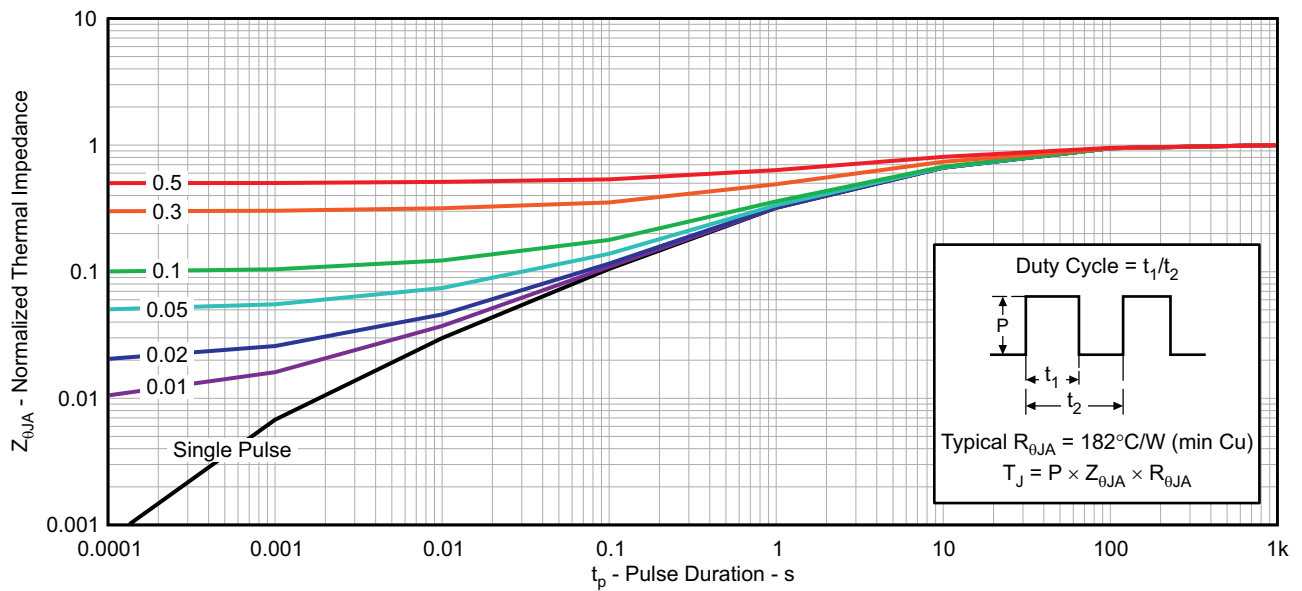
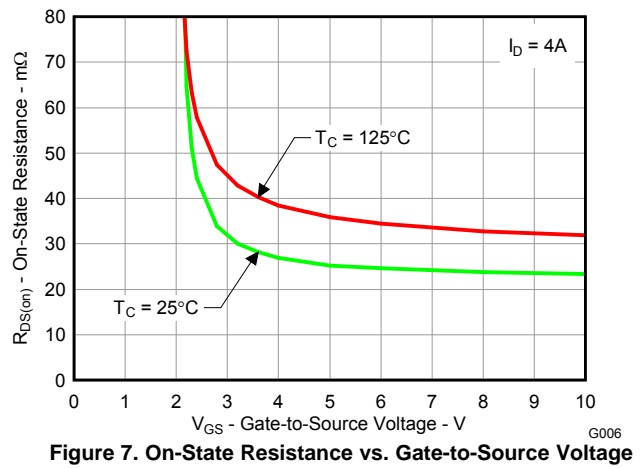
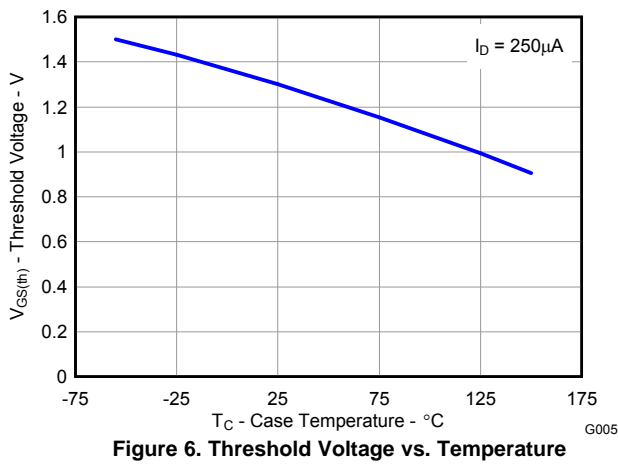
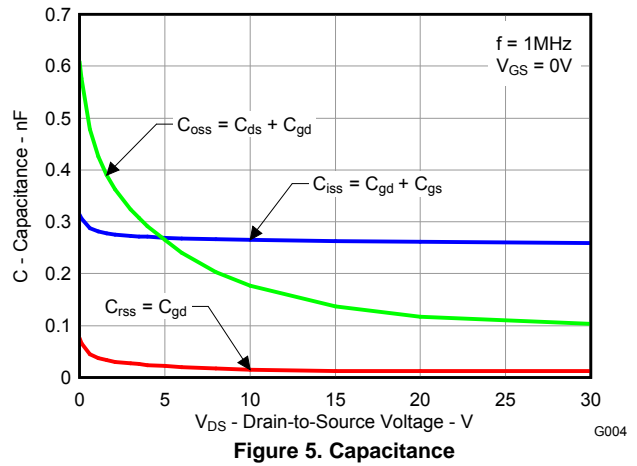
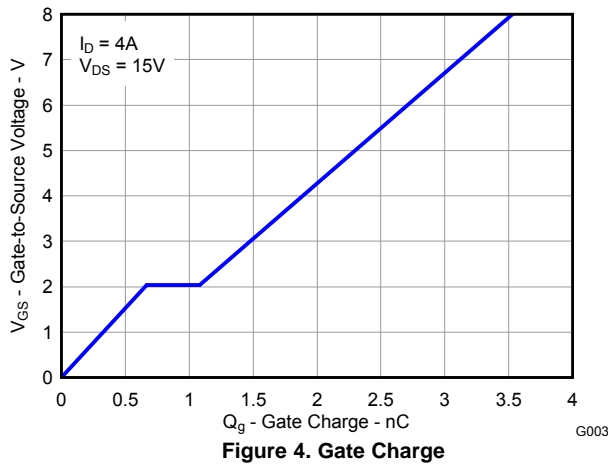
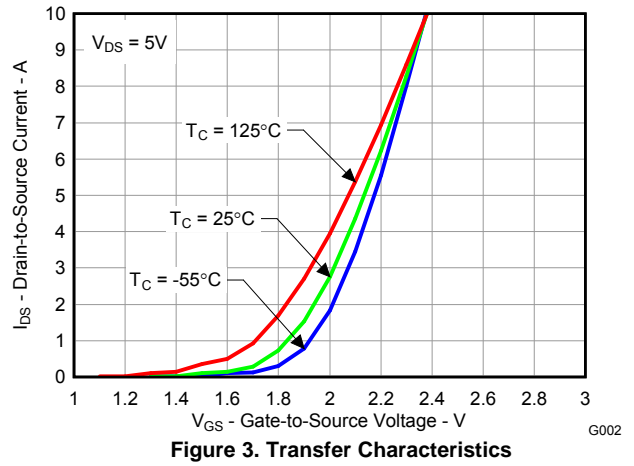
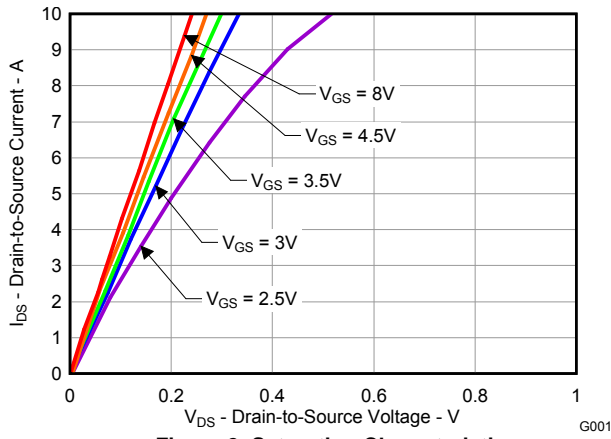


Figure 1. Transient Thermal Impedance

G012

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

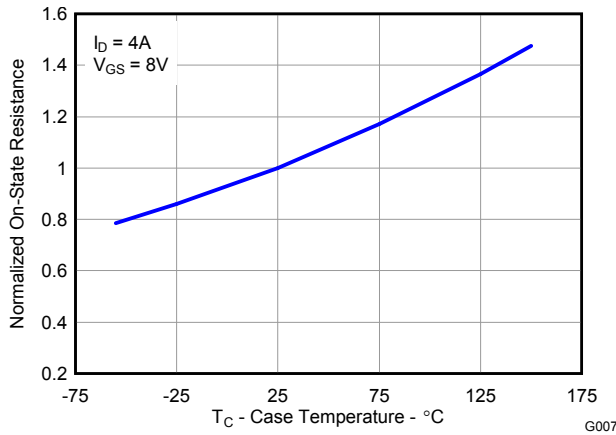


Figure 8. Normalized On-State Resistance vs. Temperature

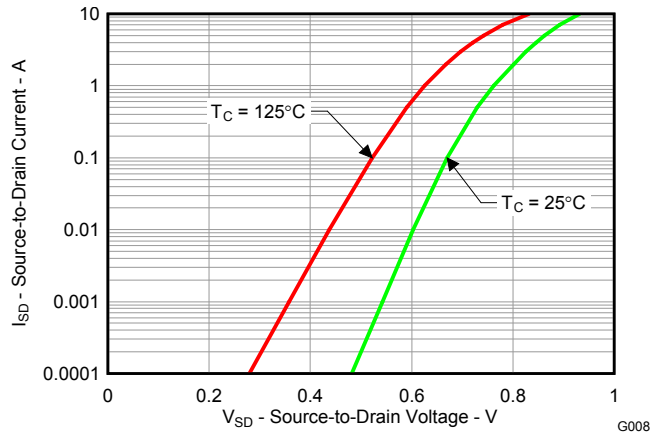


Figure 9. Typical Diode Forward Voltage

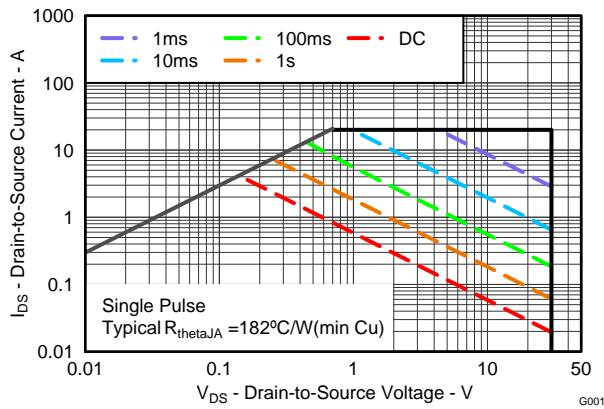


Figure 10. Maximum Safe Operating Area

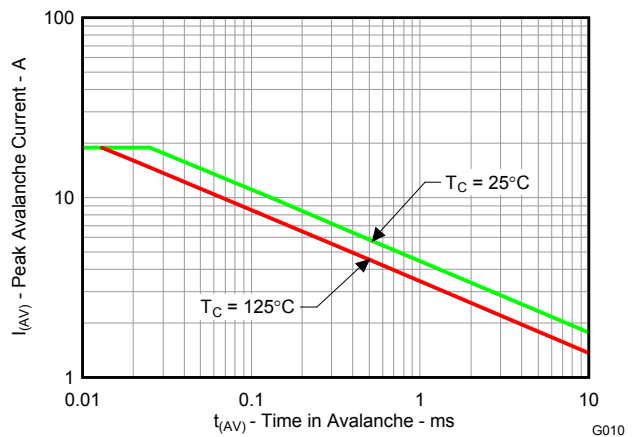


Figure 11. Single Pulse Unclamped Inductive Switching

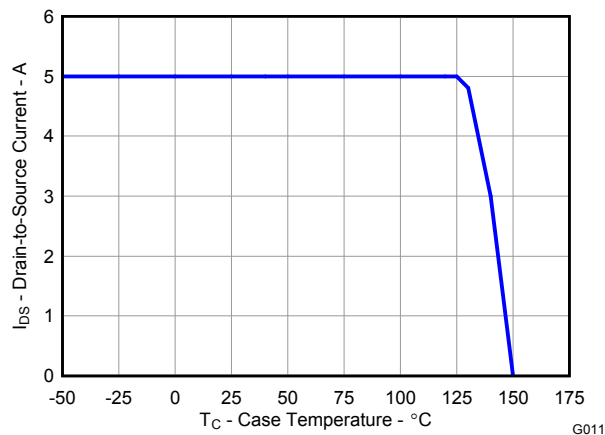
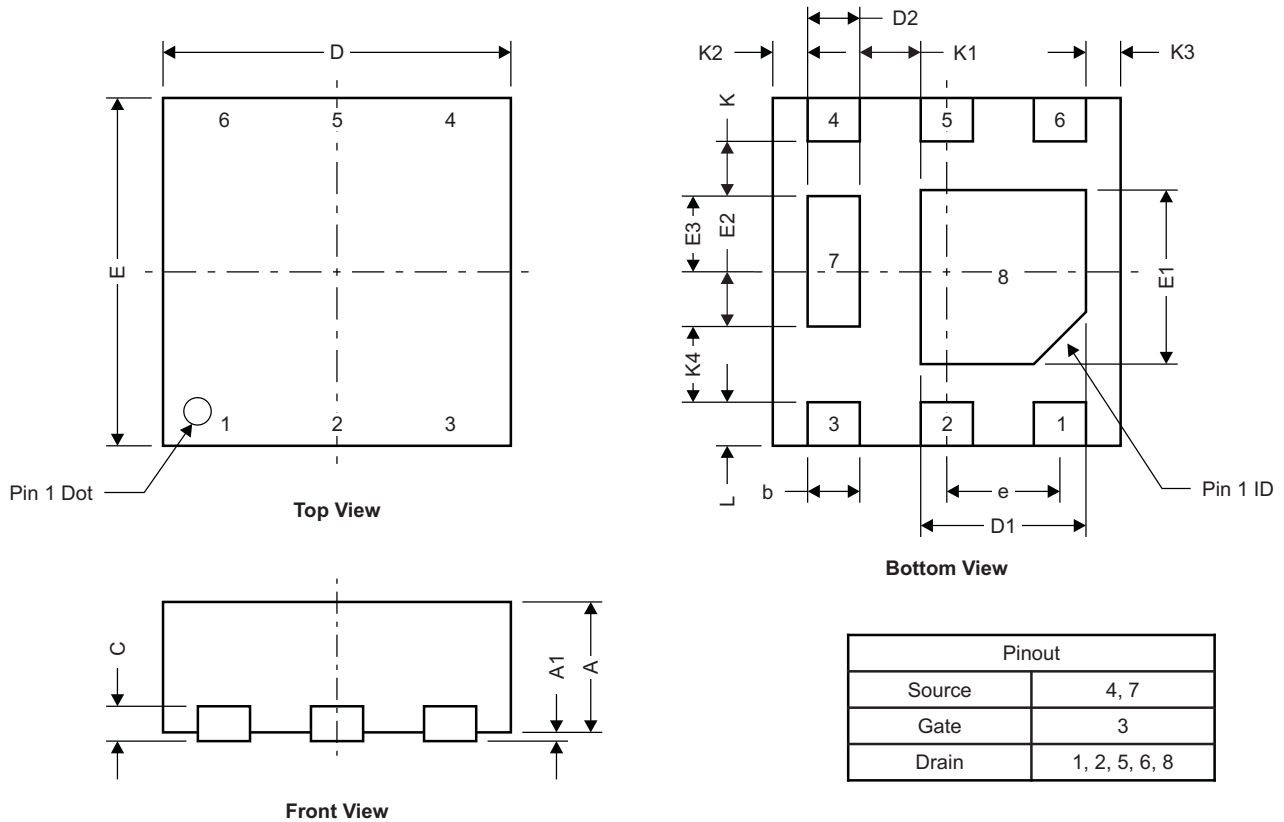


Figure 12. Maximum Drain Current vs. Temperature

MECHANICAL DATA

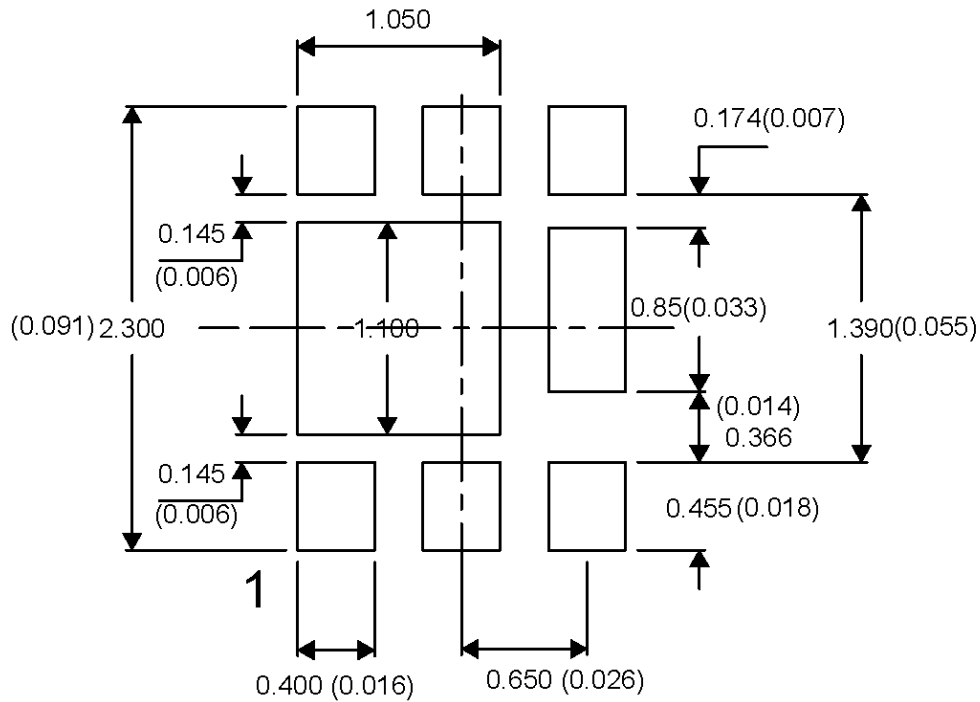
Q2 Package Dimensions



M0175-02

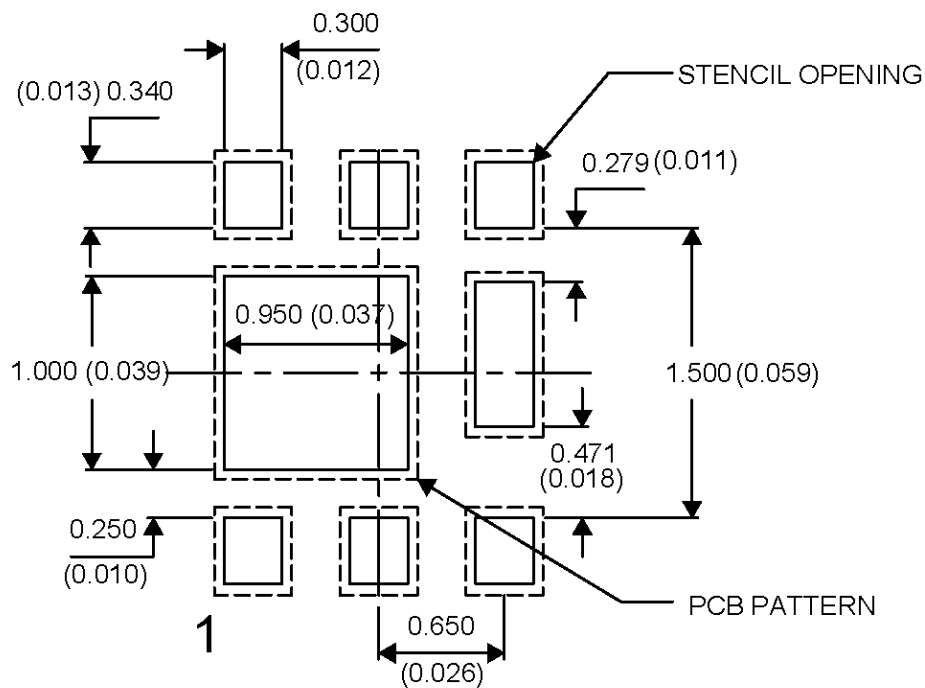
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.700	0.750	0.800	0.028	0.030	0.032
A1	0.000		0.050	0.000		0.002
b	0.250	0.300	0.350	0.010	0.012	0.014
C	0.203 TYP			0.008 TYP		
D	2.000 TYP			0.080 TYP		
D1	0.900	0.950	1.000	0.036	0.038	0.040
D2	0.300 TYP			0.012 TYP		
E	2.000 TYP			0.080 TYP		
E1	0.900	1.000	1.100	0.036	0.040	0.044
E2	0.280 TYP			0.0112 TYP		
E3	0.470 TYP			0.0188 TYP		
e	0.650 BSC			0.026 TYP		
K	0.280 TYP			0.0112 TYP		
K1	0.350 TYP			0.014 TYP		
K2	0.200 TYP			0.008 TYP		
K3	0.200 TYP			0.008 TYP		
K4	0.470 TYP			0.0188 TYP		
L	0.200	0.25	0.300	0.008	0.010	0.012

Recommended PCB Pattern



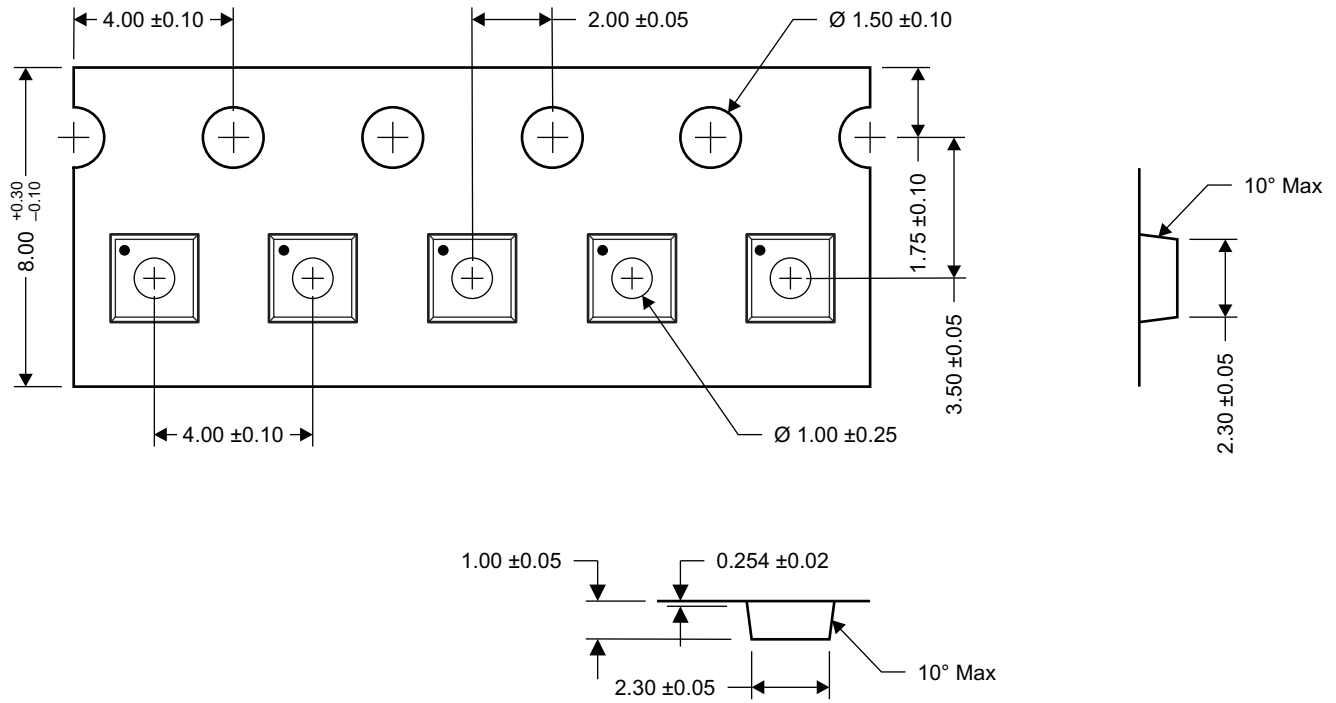
For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing through PCB Layout Techniques](#).

Recommended Stencil Pattern



Note: All dimensions are in mm, unless otherwise specified.

Q2 Tape and Reel Information



- Notes:
1. Measured from centerline of sprocket hole to centerline of pocket
 2. Cumulative tolerance of 10 sprocket holes is ± 0.20
 3. Other material available
 4. Typical SR of form tape Max 10^8 OHM/SQ
 5. All dimensions are in mm, unless otherwise specified.

REVISION HISTORY

Changes from Original (October 2012) to Revision A	Page
• Changed the device number From: CSD17313Q2-Q1 To: CSD17313Q2Q1	1
Changes from Revision A (November 2012) to Revision B	Page
• Changed the Recommended PCB Pattern	7
• Added the Recommended Stencil Pattern	7
Changes from Revision B (January 2013) to Revision C	Page
• Changed Figure 10 , Maximum Safe Operating Area	5

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
CSD17313Q2Q1	ACTIVE	SON	DQK	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-50 to 150		Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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